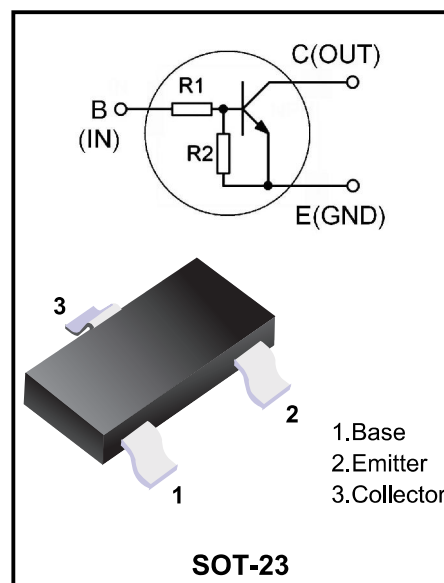


500mA NPN Digital Transistor

Features

- Built-In Biasing Resistors, $R_1 = 10k\Omega$, $R_2 = 10k\Omega$
- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors.
- Only the on/off conditions need to be set for operation, making the circuit design easy.



Marking Code

BCR533	XC
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Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Value	Unit
Supply voltage	V_{CBO}	50	V
Input voltage	V_{CEO}	50	V
Input forward voltage	V_{IF}	40	V
Input reverse voltage	V_{IR}	10	V
Output current	I_C	500	mA
Total power dissipation	P_{tot}	330	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-65~150	°C

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point	R_{thJS}	215	K/W

Note: Pb-containing package may be available upon special request

For calculation of R_{thJA} please refer to Application Note Thermal Resistance

Electrical Characteristics (Ta=25℃, unless otherwise specified)

Parameter	Symbol	Conditions	Value			Unit
			Min	Typ	Max	
Collector-base breakdown voltage	BV_{CBO}	$I_C=10\mu A, I_E=0$	50			V
Collector-emitter breakdown voltage	BV_{CEO}	$I_C=100\mu A, I_B=0$	50			V
Collector-base cutoff current	I_{CBO}	$V_{CB}=50V$			100	nA
Emitter-base cutoff current	I_{EBO}	$V_{EB}=10V$			0.75	mA
DC current gain	h_{FE}	$V_{CE}=5V, I_O=50mA$	70			
Collector-emitter saturation voltage*	$V_{CE(sat)}$	$I_C=50mA, I_B=2.5mA$			0.3	V
Input voltage	$V_{I(off)}$	$V_{CE}=5V, I_O=100\mu A$	0.6		1.5	V
	$V_{I(on)}$	$V_{CE}=0.3V, I_O=2mA$	1.0		2.5	V
Input resistor	R_1		7	10	13	KΩ
Resistor ratio	R_1/R_2		0.9	1	1.1	
Transition frequency	f_T	$V_{CE}=5V, I_E=50mA, f=100MHz$		100		MHz

* Pulse test: $t < 300\mu s$; Duty $< 2\%$

Typical Characteristics

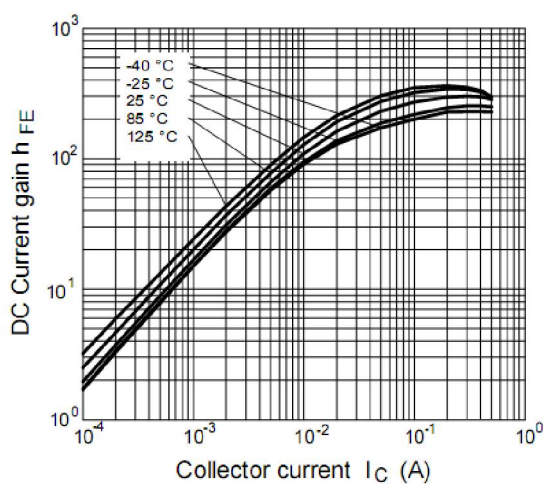


Figure 1. DC current gain

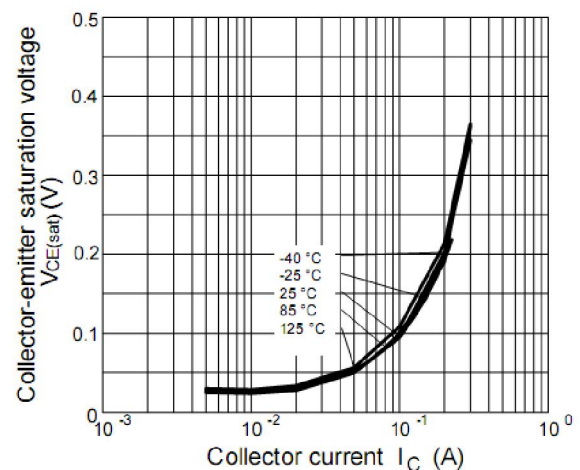


Figure2. Collector-emitter saturation voltage

Typical Characteristics

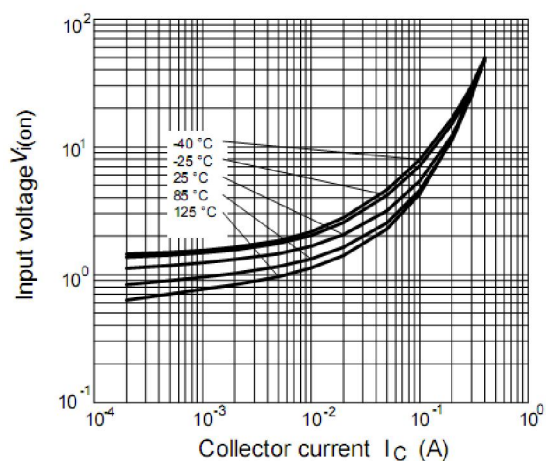


Figure 3. Input voltage vs. output current (ON characteristics)

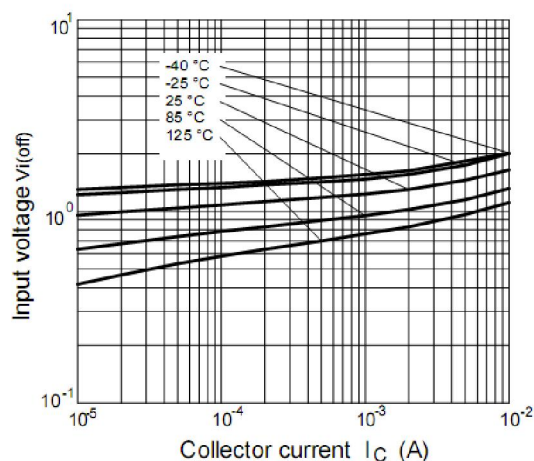


Figure 4. Output current vs. input voltage (OFF characteristics)

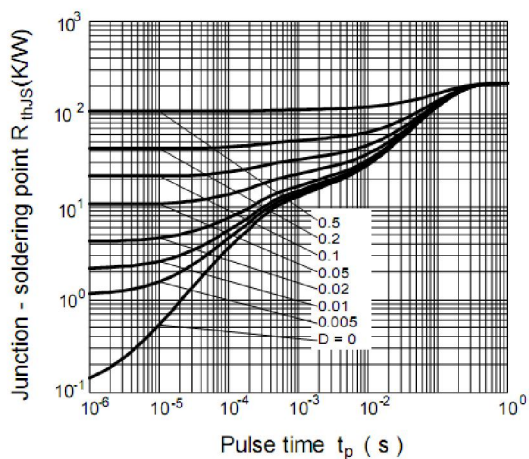


Figure 5. Permissible Pulse Load

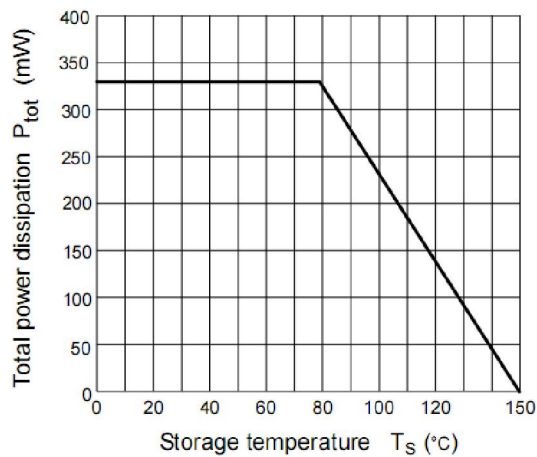


Figure 5. Total power dissipation

Ordering information

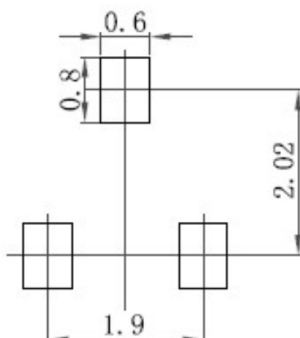
Package	Packing Description	Base Quantity	Packing Quantity
SOT-23	Tape/Reel, 7" reel	3000pcs/Reel	24000PCS/Box 120000PCS/Carton

Package Dimensions

SOT-23

Dim.	Millimeter (mm)		mil	
	Min.	Max.	Min.	Max.
A	0.9	1.15	35	45
A1	0.1		3.9	
bp	0.38	0.48	15	19
C	0.09	0.15	3.54	5.9
D	2.8	3.0	110	118
E	1.2	1.4	47	55
E	1.9		75	
E1	0.95		37	
HE	2.1	2.55	83	100
Lp	0.15	0.45	5.9	18
Q	0.45	0.55	18	22
v	0.2		7.9	
W	0.1		4	

The recommended mounting pad size



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